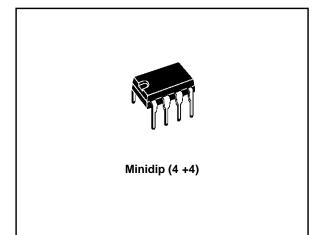


# **TDA7235**

# **1.6W AUDIO AMPLIFIER**

#### **PRODUCT PREVIEW**

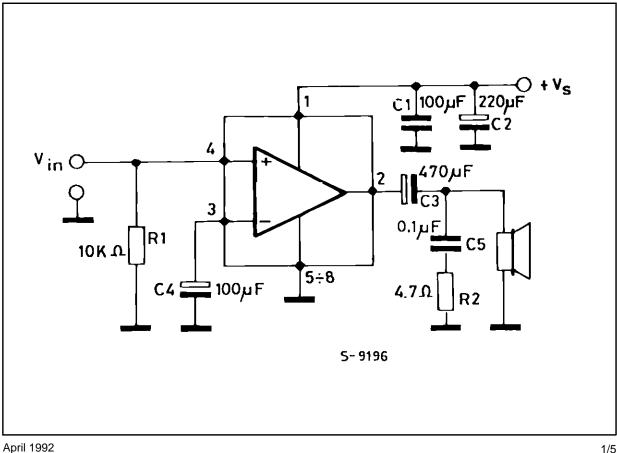
- **OPERATING VOLTAGE 1.8 TO 24V**
- LOW QUIESCENT CURRENT
- HIGH POWER CAPABILITY
- LOW CROSSOVER DISTORTION
- SOFT CLIPPING -



#### DESCRIPTION

The TDA7235 is a monolithic integrated circuit in 4 +4 lead Minidip package, intended for use as class AB power amplifier with wide range of supply voltage in portable radios, cassette recorders and players, TV sets, etc..

#### **TEST AND APPLICATION CIRCUIT**



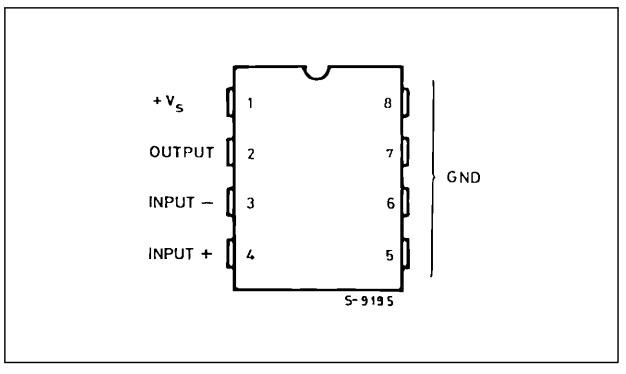
This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

# TDA7235

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	28	V
lo	Output Peak Current	1	А
P <sub>tot</sub>	Total Power Dissipation $T_{amb} = 50^{\circ}C$ $T_{case} = 70^{\circ}C$	1.25 4	W W
T <sub>stg</sub> , T <sub>j</sub>	Storage and Junction Temperature	-40 to150	°C

# **PIN CONNECTION** (Top view)



# THERMAL DATA

Symbol	Description	Value	Unit	
R <sub>th j-amb</sub>	Thermal Resistance Junction-ambient	max.	80	°C/W
R <sub>th i-case</sub>		max.	15	°C/W



Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Voltage		1.8		24	V
Vo	Quiescent Output Voltage	$V_S = 9V$ $V_S = 12V$		4 5.5		V V
ld	Quiescent Drain Current			4	10	mA
I <sub>b</sub>	Input Bias Current					
Po	Output Power	$\begin{array}{l} d = 10\% \\ V_S = 9V \\ V_S = 12V \\ R_L = 8\Omega \\ V_S = 15V \\ R_L = 16\Omega \\ V_S = 20V \\ R_L = 32\Omega \end{array}$		1.6 1.8 1.8 1.6		W W W W
d	Distortion	$P_O = 0.5W$ $R_L = 8\Omega$		0.3	1	%
Gv	Closed Loop Voltage Gain			38		dB
R <sub>in</sub>	Input Resistance		100			KΩ
e <sub>N</sub>	Total Input Noise	$R_S = 10KΩ$ b = Curve A B = 22Hz to 22KHz		2 3		μV μV
SVR	Supply Voltage Rejection	$f = 100Hz$ $R_g = 10K\Omega$	24	33		dB

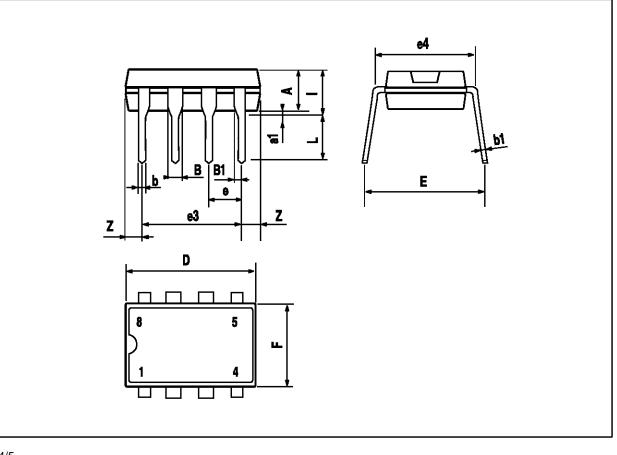
# **ELECTRICAL CHARACTERISTICS** ( $V_S = 12V$ , $T_{amb} = 25^{\circ}C$ , f = 1KHz, unless otherwise specified.)



# TDA7235

### MINIDIP PACKAGE MECHANICAL DATA

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A		3.32			0.131	
a1	0.51			0.020		
В	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
е		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
I			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060





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